TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7SL08F, TC7SL08FU

2-INPUT AND GATE

The TC7SL08 is a low voltage operative C²MOS 2-INPUT AND GATE fabricated with silicon gate C²MOS technology.

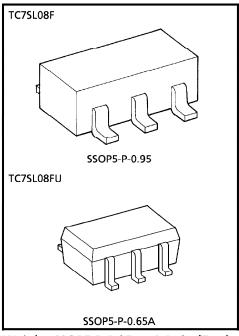
Operating voltage (V_{CC} (opr)) is 1~3V equivalent to 1pc or 2pcs of dry cell battery and it achives low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which enables high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES

- High Speed \cdots $t_{pd} = 10$ ns (Typ.) at $V_{CC} = 3V$
- Low Power Dissipation $\cdots I_{CC} = 1\mu A$ (Max.) at $Ta = 25^{\circ}C$
- High Noise Immunity $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Symmetrical Output Impedance ····· |IOH| = IOL = 1mA
- Balanced Propagation Delay Time ··· tpLH≒tpHL
- Low Voltage Operating·············V_{CC} (opr) = 1~3.6V

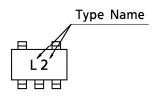


Weight SSOP5-P-0.95 : 0.016g (Typ.) SSOP5-P-0.65A : 0.006g (Typ.)

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	Vcc	-0.5~5	V
DC Input Voltage	VIN	-0.5~V _{CC} +0.5	V
DC Output Voltage	Vout	-0.5~V _{CC} +0.5	V
Input Diode Current	ΙΚ	± 20	mA
Output Diode Current	lok	± 20	mA
DC Output Current	IOUT	± 12.5	mA
DC V _{CC} / Ground Current	lcc	± 25	mA
Power Dissipation	PD	200	mW
Storage Temperature	T _{stg}	-65∼150	°C
Lead Temperature (10s)	TL	260	°C

MARKING



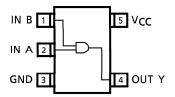
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LOGIC DIAGRAM

PIN CONNECTION (TOP VIEW)





RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	1~3.6	V
Input Voltage	V _{IN}	0~V _{CC}	V
Output Voltage	VOUT	0~V _{CC}	V
Operating Temperature	T _{opr}	- 40~85	°C
		$0 \sim 1000 (V_{CC} = 1.0V)$	
Input Rise and Fall Time	t _r , t _f	$0\sim 500 (V_{CC} = 1.5V)$	ns
		0~ 400 (V _{CC} = 3.0V)	

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC SYMBOL		TEST CIR-	TEST CONDITION		Ta = 25°C			Ta = -4	a = - 40~85°C		
CHARACTERISTIC	STIVIBOL	CUIT	11231	1251 CONDITION		MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High-Level Input					1.0	0.75	_	_	0.75	_	
Voltage	VIH	—		_	1.5	1.05	—	—	1.05	—	V
					3.0	2.10	_	_	2.10		
Low-Level Input					1.0	. —		0.25	<u> </u>	0.25	
Voltage	V _{IL}	_	_		1.5	_	_	0.45	—	0.45	V
Voltage					3.0	_	_	0.90	—	0.90	
					1.0	0.9	1.0	l —	0.9		
High Lovel				$I_{OH} = -20 \mu A$	1.5	1.4	1.5	l —	1.4		
High-Level	Voн	—	- V _{IN} = V _{IH}		3.0	2.9	3.0	l —	2.9	_	V
Output Voltage				I _{OH} = -1mA	1.5	1.07	1.23	—	0.99	_	
				$I_{OH} = -2.6mA$	3.0	2.61	2.68	 	2.55	_	
			$V_{IN} = V_{IH}$ or V_{IL} $I_{OL} = 20 \mu A$ $I_{OL} = 1 mA$ $I_{OL} = 2.6 mA$		1.0	_	0.0	0.1	_	0.1	
l avv laval				1.5	—	0.0	0.1	 —	0.1		
Low-Level	VOL	_			3.0	—	0.0	0.1	l —	0.1	V
Output voitage	Output Voltage			I _{OL} = 1mA	1.5	_	0.23	0.31	_	0.37	
				$I_{OL} = 2.6 mA$	3.0	-	0.23	0.31	 	0.33	
Input Leakage	IN	_	V _{IN} = V _{CC}	or GND	3.6			±0.1		± 1.0	
Current	אווי		AIN - ACC	C. GIVD	3.0					_ 1.0	,,,
Quiescent Supply Current	lcc	_	$V_{IN} = V_{CC}$	or GND	3.6	_	_	1.0	_	10.0	μΑ

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AC ELECTRICAL CHARACTERISTICS (C	$C_L = 15 pF$, Ir	$nput t_r = t_f = 6ns$,	$V_{CC} = 3.3 \pm 0.3 \text{V}$
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CHARACTERISTIC	TEST		TEST CONDITION		UNIT			
CHARACTERISTIC	STIVIBOL	CUIT	1E31 CONDITION	MIN.	TYP.	MAX.	ONIT	
Output Transition	tTLH				5.0	9.0	ns	
Time	tTHL	_	1		3.0	9.0	115	
Propagation	^t PLH				7.5	13.0	nc	
Delay Time	t _{PHL}		1	_	7.5	13.0	ns	

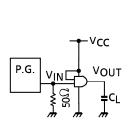
AC ELECTRICAL CHARACTERISTICS ($C_L = 25pF$, Input $t_r = t_f = 6ns$)

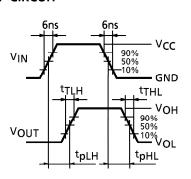
CHARACTERISTIC SYMB	SYMBOL	TEST	TEST CONDITION		Т	Ta = 25°C			Ta = − 40~85°C		
CHARACTERISTIC	STIVIBOL	CIR- CUIT		V_{CC}	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT	
Output Transition	4			1.0	_	70	170	_	240		
Output Transition Time	t _{TLH}	_	_	1.5		25	45	<u> </u>	55	ns	
Time	tTHL			3.0		10	15		20		
Proposition	4			1.0	_	70	170	_	210		
Propagation Delay Time	t _{PLH}	—	_	1.5	_	25	45	l —	55	ns	
Delay Time	t _{PHL}			3.0	_	10	15	_	20		
Input Capacitance	CIN	_	_		_	5	10		10		
Power Dissipation	Coo		Note (1)			10				pF	
Capacitance	C _{PD}		Note (1)			10					

Note (1): CpD defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test Circuit).

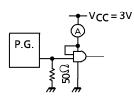
Average operating current can be obtained by the equation as follows. $I_{CC}(opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST CIRCUIT





ICC (opr) TEST CIRCUIT

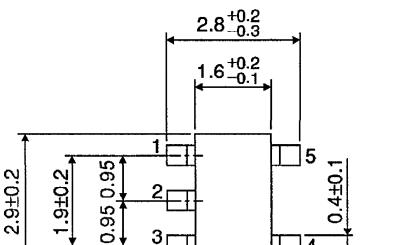


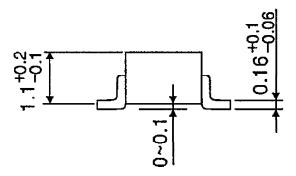
Input waveform is the same as that in case of switching characteristics test.

Unit: mm

OUTLINE DRAWING

SSOP5-P-0.95



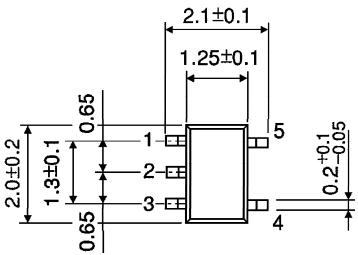


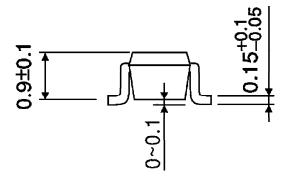
Weight: 0.016g (Typ.)

Unit: mm

OUTLINE DRAWING

SSOP5-P-0.65A





Weight: 0.006g (Typ.)